



PN4250



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 68. See PN200 for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
Vcbo	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	5.0	V
lc	Collector Current - Continuous	500	mA
TJ, Tstg	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

R_{0JA}

Thermal Resistance, Junction to Ambient

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted			
Symbol	Characteristic	Max	Units
		PN4250	
PD	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W

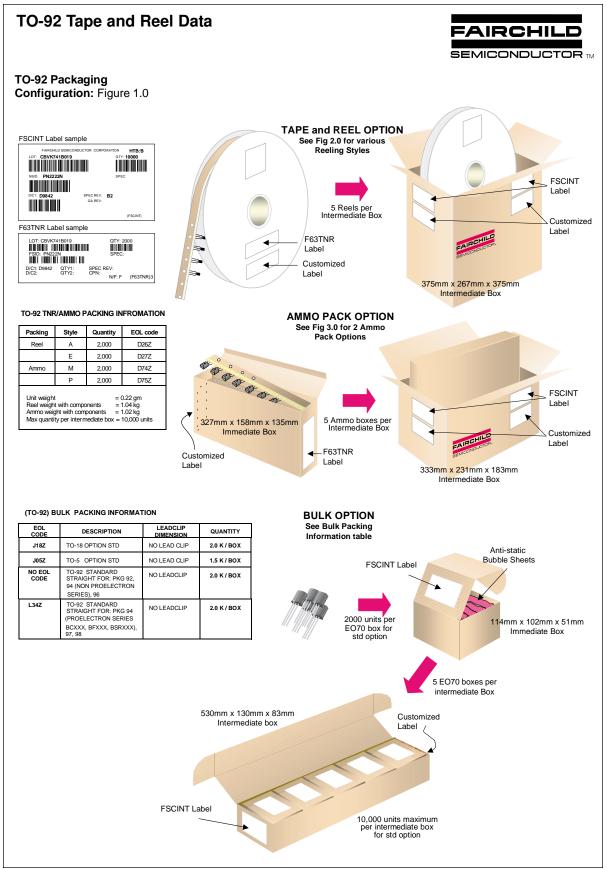
200

°C/W

PNP General Purpose Amplif

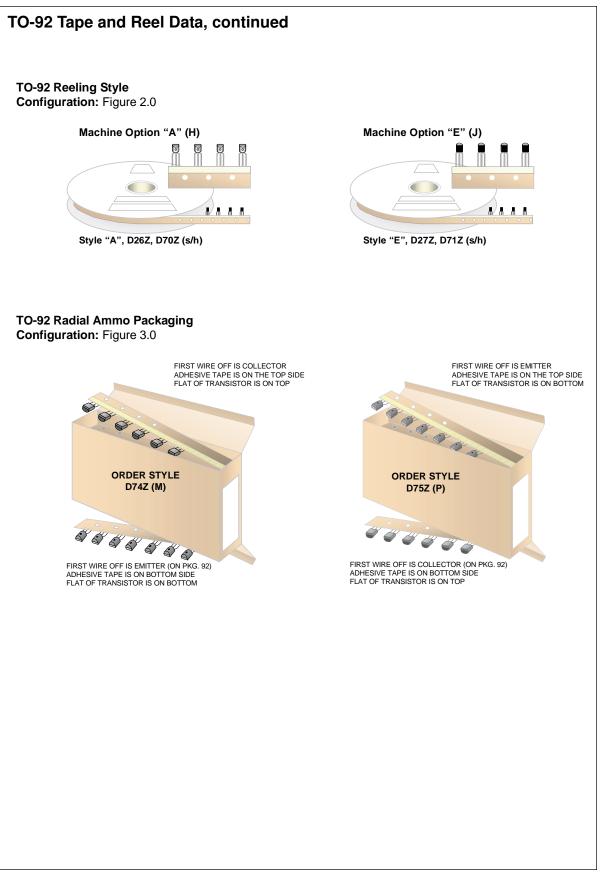
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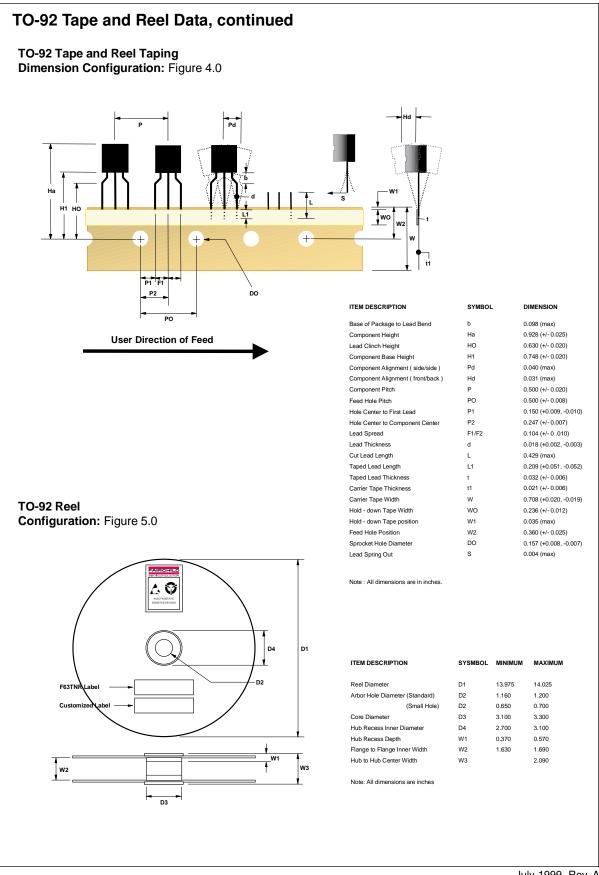
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 5.0 \text{ mA}, I_{\rm B} = 0$	40		V
V _{(BR)CES}	Collector-Emitter Breakdown Voltage*	$I_{C} = 10 \ \mu A, \ I_{B} = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 10 \ \mu A, \ I_{E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \ \mu A, \ I_C = 0$	5.0		V
Ісво	Collector-Cutoff Current	$V_{CB} = 40 \text{ V}, I_E = 0$		10	nA
I _{EBO}	Emitter-Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		20	nA
h _{FE}	ACTERISTICS* DC Current Gain	V _{CE} = 5.0 V, I _C = 100 μA	250	700	
h _{FE}	DC Current Gain		250		V
		$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \ \mu\text{A}$ Ic = 10 mA, I _B = 0.5 mA	250	700 0.25	V
h _{FE} V _{CE(sat)}	DC Current Gain Collector-Emitter Saturation Voltage	Ic = 10 mA, I _B = 0.5 mA	250	0.25	
h _{FE} V _{CE(sat)} SMALL S	DC Current Gain Collector-Emitter Saturation Voltage IGNAL CHARACTERISTICS Output Capacitance	$I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA}$ $V_{CB} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$		6.0	V PF
h _{FE} V _{CE(sat)} SMALL S Cob	DC Current Gain Collector-Emitter Saturation Voltage IGNAL CHARACTERISTICS Output Capacitance Input Impedance	Ic = 10 mA, I _B = 0.5 mA V _{CB} = 5.0 V, f = 1.0 MHz V _{CE} = 5.0 V, I _C = 1.0 mA,	6.0	6.0 20	pF kΩ
h _{FE} V _{CE(sat)} SMALL S Cob hie	DC Current Gain Collector-Emitter Saturation Voltage IGNAL CHARACTERISTICS Output Capacitance Input Impedance Output Admittance	$I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA}$ $V_{CB} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$		6.0 20 50	pF kΩ μmhos
hFE VCE(sat) SMALL S Cob Nie Noe Nre	DC Current Gain Collector-Emitter Saturation Voltage IGNAL CHARACTERISTICS Output Capacitance Input Impedance Output Admittance Voltage Feedback Ratio	$I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA}$ $V_{CB} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA},$ $f = 1.0 \text{ kHz}$	6.0	6.0 20 50 10	pF kΩ μmhos x10 ⁻⁴
h _{FE} V _{CE(sat)}	DC Current Gain Collector-Emitter Saturation Voltage IGNAL CHARACTERISTICS Output Capacitance Input Impedance Output Admittance	Ic = 10 mA, I _B = 0.5 mA V _{CB} = 5.0 V, f = 1.0 MHz V _{CE} = 5.0 V, I _C = 1.0 mA,	6.0	6.0 20 50	pF kΩ μmhos



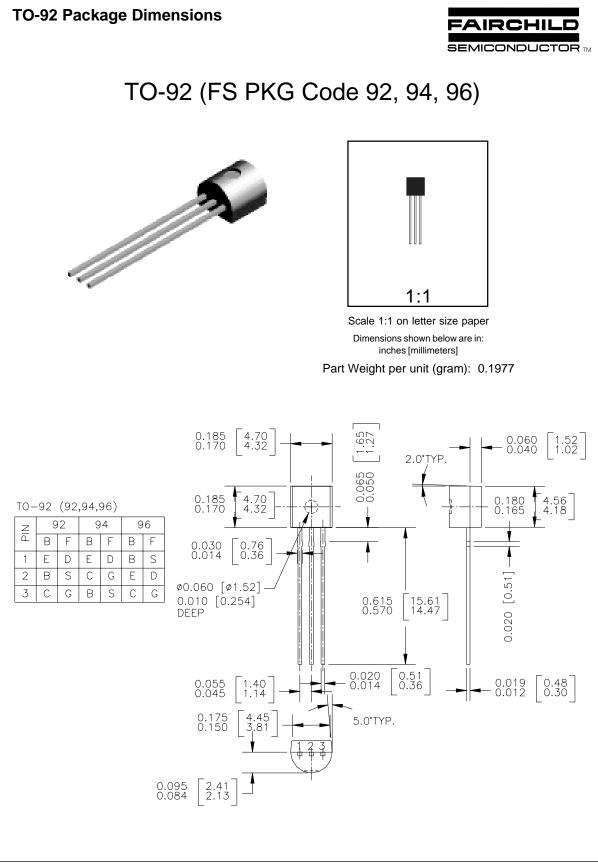
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